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PATENT

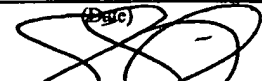
IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Raina et al.  
Appl. No. : 10/644,443  
Filed : August 19, 2003  
For : NITROGEN AND  
PHOSPHOROUS DOPED  
AMORPHOUS SILICON AS  
RESISTOR FOR FIELD  
EMISSION DISPLAY DEVICE  
BASEPLATE  
Examiner : Roy, Sikha  
Group Art Unit : 2879

CERTIFICATE OF MAILING

I hereby certify that this correspondence and all marked attachments are being mailed via Express Mail #EV 309079712 US in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on

February 1, 2005

(Date)  
  
Sabing H. Lee, Reg. No. 43,745

RESPONSE TO OFFICE ACTION

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

In response to the Office Action mailed on December 1, 2004, please amend the above-captioned application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 4 of this paper.

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